

MOS FIELD EFFECT TRANSISTOR
2SK3663

N-CHANNEL MOS FIELD EFFECT TRANSISTOR
FOR SWITCHING

DESCRIPTION

The 2SK3663 is a switching device which can be driven directly by a 2.5 V power source.

The 2SK3663 features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

FEATURES

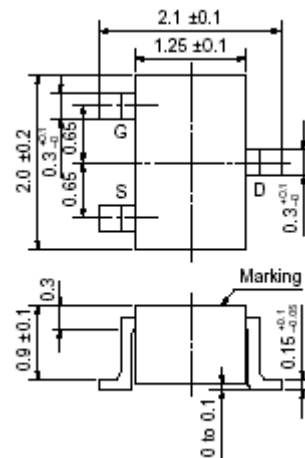
- 2.5 V drive available
- Low on-state resistance
 $R_{DS(on)1} = 0.57 \Omega$ MAX. ($V_{GS} = 4.5 V, I_D = 0.30 A$)
 $R_{DS(on)2} = 0.60 \Omega$ MAX. ($V_{GS} = 4.0 V, I_D = 0.30 A$)
 $R_{DS(on)3} = 0.88 \Omega$ MAX. ($V_{GS} = 2.5 V, I_D = 0.15 A$)

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3663	SC-70 (SSP)

Remark Marking : G26

PACKAGE DRAWING (Unit: mm)

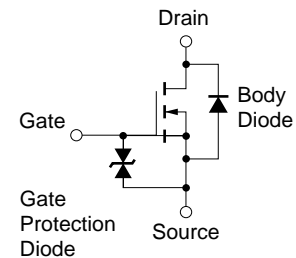


ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ C$)

Drain to Source Voltage ($V_{GS} = 0 V$)	V_{DSS}	20	V
Gate to Source Voltage ($V_{DS} = 0 V$)	V_{GSS}	±12	V
Drain Current (DC)	$I_D (DC)$	±0.5	A
Drain Current (pulse) ^{Note1}	$I_D (pulse)$	±2.0	A
Total Power Dissipation ^{Note2}	P_T	0.2	W
Channel Temperature	T_{ch}	150	°C
Storage Temperature	T_{stg}	-55 to +150	°C

- Notes 1. $PW \leq 10 \mu s$, Duty Cycle $\leq 1\%$
 2. Mounted on FR-4 board of $2500 mm^2 \times 1.1 mm$

EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

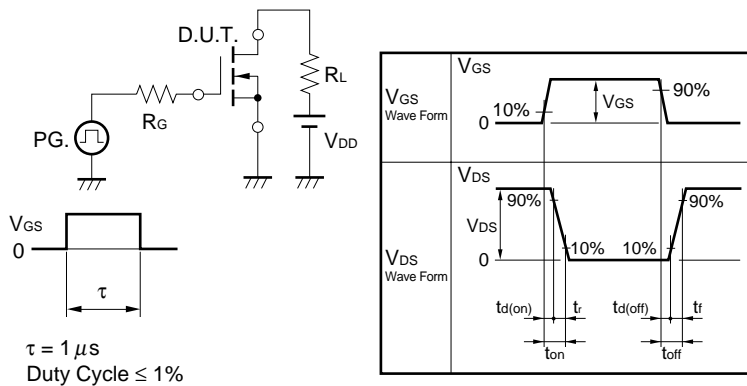
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ELECTRICAL CHARACTERISTICS (T_A = 25°C)

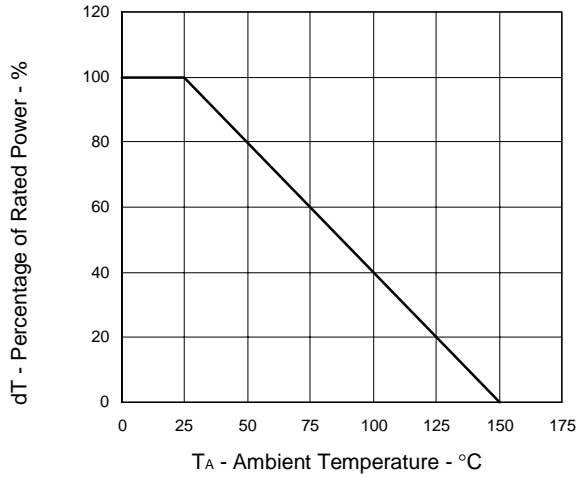
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 20 V, V _{GS} = 0 V			1.0	μA
Gate Leakage Current	I _{GSS}	V _{GS} = ±12 V, V _{DS} = 0 V			±10	μA
Gate Cut-off Voltage ^{Note}	V _{GS(off)}	V _{DS} = 10 V, I _D = 1.0 mA	0.5	1.0	1.5	V
Forward Transfer Admittance ^{Note}	y _{fs}	V _{DS} = 10 V, I _D = 0.30 A	0.25	0.75		S
Drain to Source On-state Resistance ^{Note}	R _{DS(on)1}	V _{GS} = 4.5 V, I _D = 0.30 A		0.38	0.57	Ω
	R _{DS(on)2}	V _{GS} = 4.0 V, I _D = 0.30 A		0.41	0.60	Ω
	R _{DS(on)3}	V _{GS} = 2.5 V, I _D = 0.15 A		0.60	0.88	Ω
Input Capacitance	C _{iss}	V _{DS} = 10 V		28		pF
Output Capacitance	C _{oss}	V _{GS} = 0 V		11		pF
Reverse Transfer Capacitance	C _{rss}	f = 1.0 MHz		7		pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 10 V, I _D = 0.30 A		20		ns
Rise Time	t _r	V _{GS} = 4.0 V		51		ns
Turn-off Delay Time	t _{d(off)}	R _G = 10 Ω		94		ns
Fall Time	t _f			87		ns
Body Diode Forward Voltage	V _{F(S-D)}	I _F = 0.5 A, V _{GS} = 0 V		0.87		V

Note Pulsed : PW ≤ 350 μs, Duty Cycle ≤ 2%

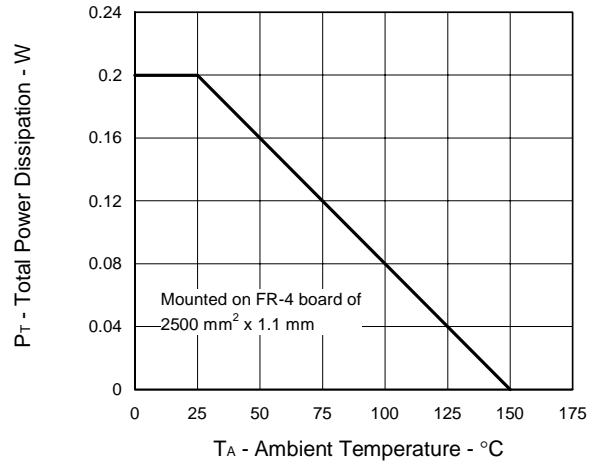
TEST CIRCUIT SWITCHING TIME



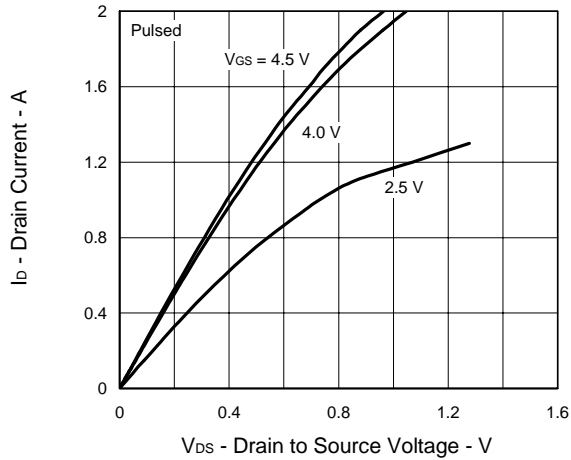
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



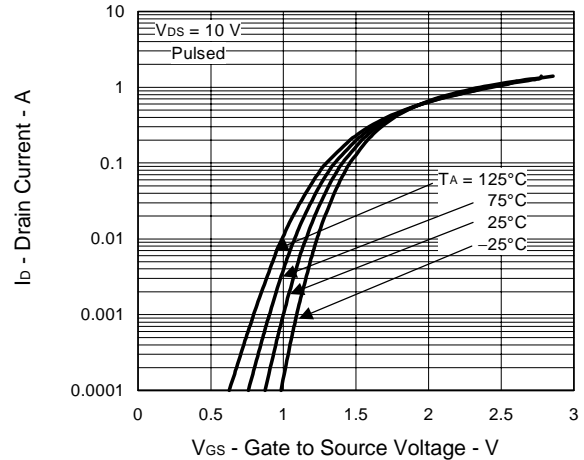
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



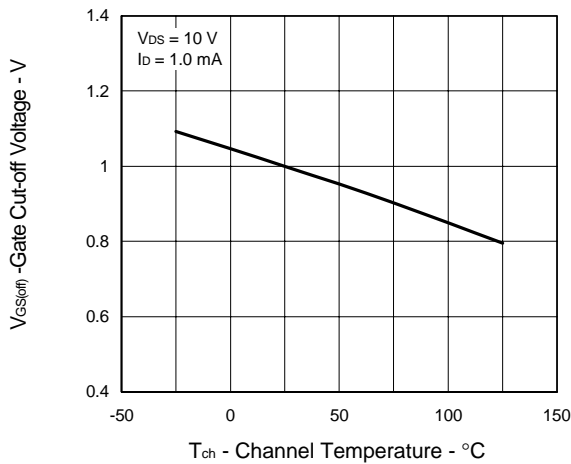
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



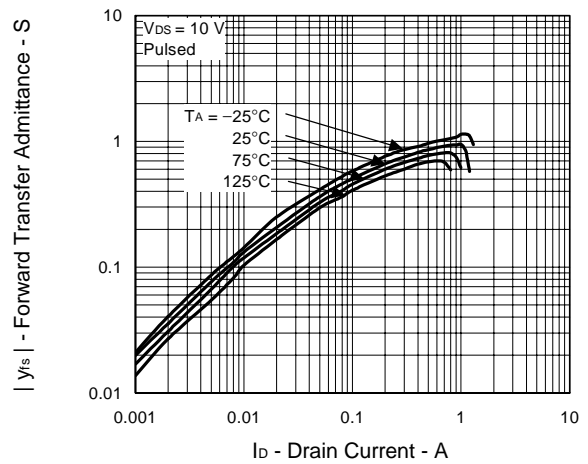
FORWARD TRANSFER CHARACTERISTICS



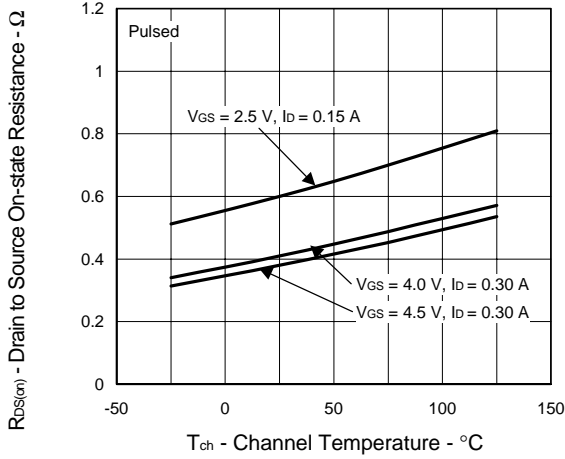
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



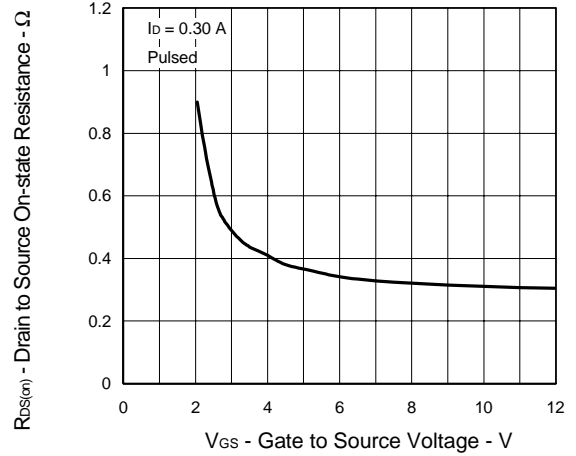
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



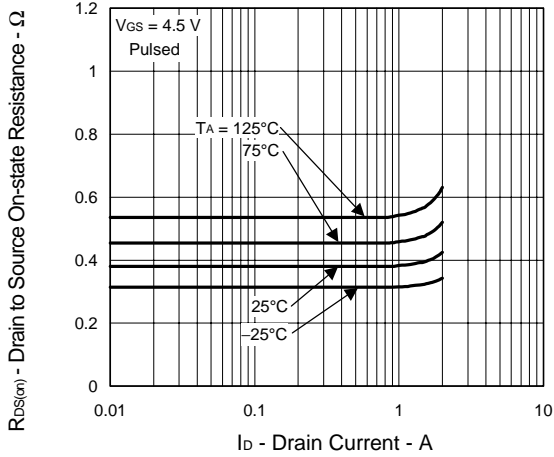
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



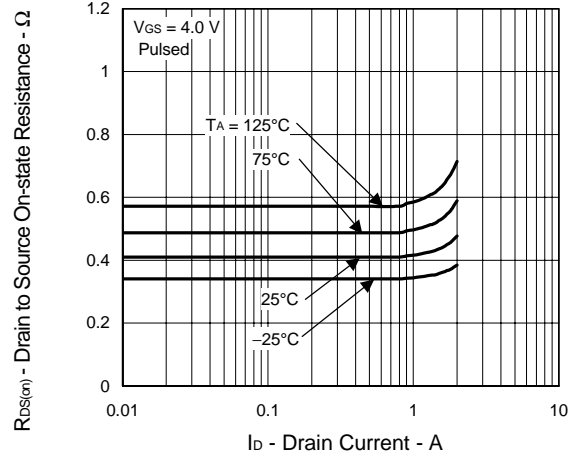
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



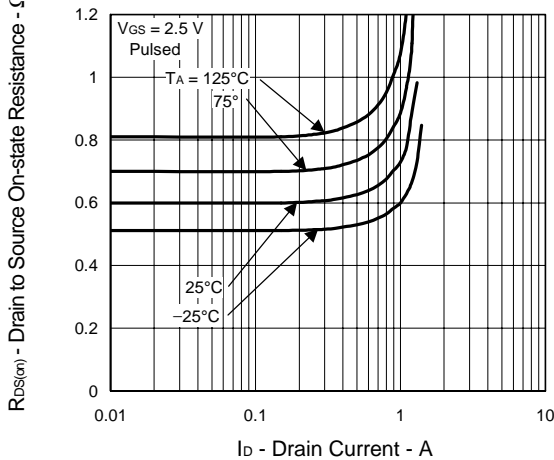
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



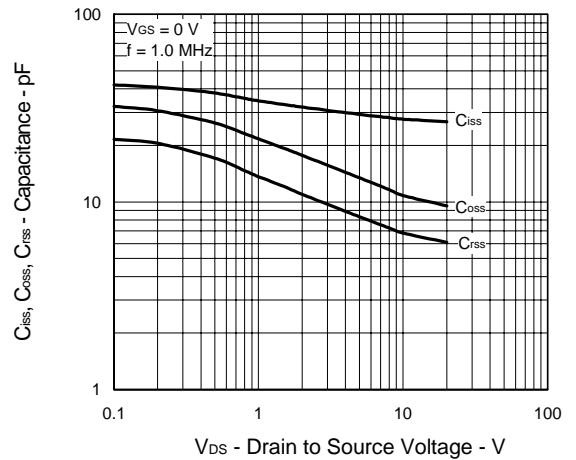
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



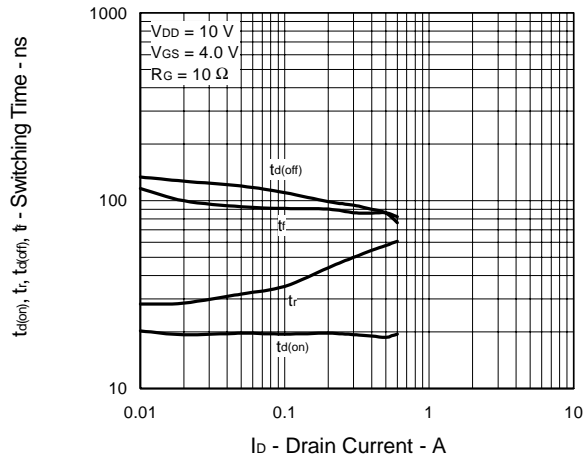
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



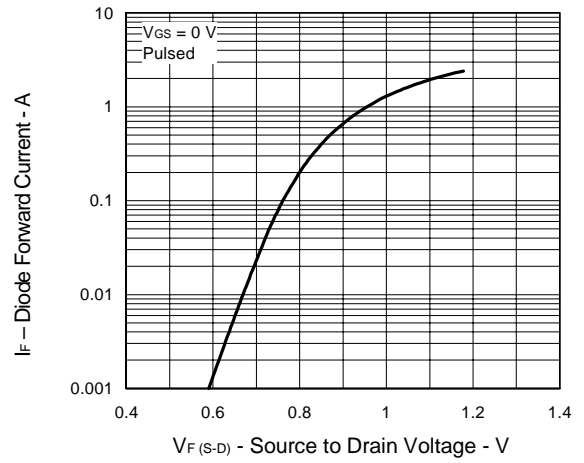
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



SWITCHING CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



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